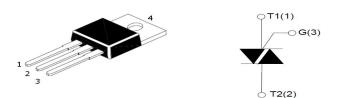




# **16A TRIACS**



BTA16-600/800/1200 TO-220 (Ins) Plastic Package

BTB16-600/800/1200 TO-220 (Non-Ins) Plastic Package

BTA16 series triacs, with high ability to withstand the shock loading of large current, provide high dv/dt rate with strong resistance to electromagnetic interface. With high commutation performances, 3 quadrant products expecially recommended for use on inductive load.

#### ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	VALUE	UNIT
Storage junction te	emperature range	T <sub>stg</sub>	-40 to 150	°C
Operating junction temperature range		Тј	-40 to 125	°C
Repetitive peak off-state voltage (T <sub>j</sub> =25°C)		V <sub>DRM</sub>	600/800/1200	V
Repetitive peak re	verse voltage (T <sub>j</sub> =25°C)	V <sub>RRM</sub>	600/800/1200	V
Non repetitive surg	ge peak Off-state voltage	V <sub>DSM</sub>	V <sub>DRM</sub> +100	V
Non repetitive peak re	verse voltage	V <sub>RSM</sub>	V <sub>RRM</sub> +100	V
RMS on-state	TO-220 (Ins) (T <sub>c</sub> =86°C)			
current	TO-220 (Non-Ins) (T <sub>c</sub> =107°C)	I <sub>T(RMS)</sub>	16	A
Non repetitive surg (full cycle, F=50Hz	ge peak on-state current )	I <sub>TSM</sub>	160	А
l <sup>2</sup> t value for fusing	(t <sub>p</sub> =10ms)	l²t	128	A <sup>2</sup> s
Critical rate of rise of on-state current $(I_{G} = 2 \times I_{GT})$		dl/dt	50	A/µs
Peak gate current		I <sub>GM</sub>	4	А
Average gate power dissipation		P <sub>G(AV)</sub>	1	W
Peak gate power		P <sub>GM</sub>	5	



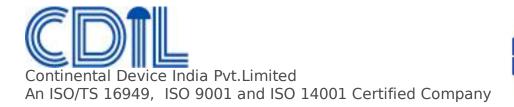
### **ELECTRICAL CHARACTERISTICS** ( $T_j=25$ °c unless otherwise specified)

#### 3 Quadrants (V <sub>DRM</sub> /V <sub>RRM</sub> : 600/800V)

PARAMETER	TEST CONDITIONS	SYMBOL	QUADRANT		VALUES				
				BW	CW	SW	TW		
Gate Trigger Current	1210 220	Ι <sub>GT</sub>	-    -	<50	<35	<10	<5	mA	
Gate Trigger Voltage	$V_{\rm D} = 12V R_{\rm L} = 33\Omega$	V <sub>GT</sub>	-    -		<1.3			V	
Off-State Gate Voltage	$V_{D} = V_{DRM} T_{j} = 125^{\circ}C$ $R_{L} = 3.3 K\Omega$	V <sub>GD</sub>	-    -	>0.2			V		
			-	<70	<50	<30	<15		
Latching Current	$I_{G} = 1.2I_{GT}$	IL.	II	<80	<60	<40	<20	<20 mA	
Holding Current	I <sub>T</sub> =100mA	I <sub>H</sub>		<60	<40	<25	<15	mA	
Critical Rate of Rise of Off-State Voltage	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C	dV/dt		>1000	>500	>200	>100	V/µs	

#### 4 Quadrant (V <sub>DRM</sub>/V <sub>RRM</sub>: 600/800V)

PARAMETER	TEST CONDITIONS	SYMBOL	QUADRANT	VALU	UNITS		
				В	С		
Gate Trigger		or	-    -	<50	<25	mA	
Current		IGT	IV	<70	<50		
Gate Trigger Voltage	$V_{\rm D} = 12V R_{\rm L} = 33\Omega$	V <sub>GT</sub>	ALL	<1.5		V	
Off-State Gate Voltage	$V_{D} = V_{DRM} T_{j} = 125^{\circ}C \qquad R_{L}$ $= 3.3K\Omega$	V <sub>GD</sub>	ALL	>0.2		V	
Latching Current	$I_{G} = 1.2I_{GT}$	IL.	I - III - IV	<70	<50	— mA	
				<100	<80		
Holding Current	olding Current I <sub>T</sub> =100mA			<60 <40		mA	
Critical Rate of Rise of Off-State Voltage	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C	dV/dt		>500	>200	V/µs	





## 3 Quadrants (V <sub>DRM</sub>/V <sub>RRM</sub>: 1200V)

PARAMETER	TEST CONDITIONS	SYMBOL	QUADRANT	VALUES	UNITS
Gate Trigger Current	V -12V220	Ι <sub>GT</sub>	-    -	<50	mA
Gate Trigger Voltage	$V_{D} = 12V R_{L} = 33\Omega$	V <sub>GT</sub>	-    -	<1.5	V
Off-State Gate Voltage	$V_{D} = V_{DRM} T_{j} = 125 ^{\circ} C$ $R_{L} = 3.3 K \Omega$	$V_{GD}$	-    -	>0.2	V
Latching Current	$I_{G} = 1.2I_{GT}$	١ <sub>L</sub>	-	<70 <90	mA
Holding Current	I <sub>T</sub> =100mA	I <sub>н</sub>		<60	mA
Critical Rate of Rise of Off-State Voltage	V <sub>D</sub> =2/3V <sub>DRM</sub> Gate Open T <sub>j</sub> =125°C	dV/dt		>1500	V/µs

#### **STATIC CHARACTERISTICS**

PARAMETER	TEST CONDITIONS		SYMBOL	VALUE (MAX)			UNITS
FARAMETER				-600V	-800V	-1200V	
On-State Voltage	I <sub>TM</sub> =22.5A t <sub>p</sub> =380μs	T <sub>j</sub> =25°C	V <sub>TM</sub>	1.5			V
Off-State Leakage	$V_{\rm d} = V_{\rm drm}$ , $V_{\rm r} = V_{\rm rrm}$	T <sub>j</sub> =25°C	I <sub>DRM</sub>	5	5	10	μΑ
Current	$v_{\rm D} = v_{\rm DRM}$ , $v_{\rm R} = v_{\rm RRM}$	T <sub>j</sub> =125°C	<sub>RRM</sub>	2	2	1	mA

#### THERMAL RESISTANCES

PARAMETER	SYMBOL	VALUE (MAX)	UNITS
Maximum Thermal TO-220 (Ins)	D	2.1	°C 111
Resistance TO-220 (Non-Ins)	K <sub>th(j-c)</sub>	1.2	°C/W

#### **ORDERING INFORMATION**

BTA12-XY								
BTB12-XY								
$X = 600: VDRM/VRRM \ge 600$	$\mathbf{Y} = BW: I_{GT1-3} \le 50mA$							
= 800: VDRM/VRRM ≥ 800	= CW: I <sub>GT1-3</sub> ≤ 35mA							
= 1200: VDRM/VRRM ≥ 1200	$=$ SW: I <sub>GT1-3</sub> $\leq$ 10mA							
	= TW: I <sub>GT1-3</sub> ≤ 5mA							
	= B: I <sub>GT1-3</sub> ≤50mA  I <sub>GT4</sub> ≤70mA							
	= C: I <sub>GT1-3</sub> ≤25mA I <sub>GT4</sub> ≤50mA							



Inches

Тур.

0.1

0.148

45°

Max.

0.181

0.035

0.028

0.052

0.107

0.382

0.409

0.260

1.173

0.067

0.116

Min.

0.173

0.024

0.018

0.048

0.094

0.339

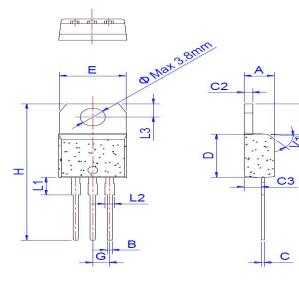
0.378

0.244

1.102

0.045

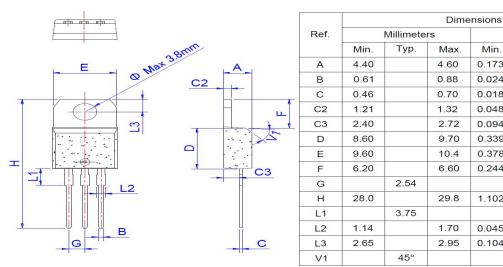
0.104



#### **TO-220 (Ins) PACKAGE OUTLINE AND DIMENSIONS**

		Dimensions							
	Ref.		Millimeters			Inches			
		Min.	Тур.	Max.	Min.	Тур.	Max.		
	A	4.40		4.60	0.173		0.181		
	В	0.61		0.88	0.024		0.035		
_	С	0.46		0.70	0.018		0.028		
-	C2	1.21		1.32	0.048		0.052		
	C3	2.40		2.72	0.094		0.107		
	D	8.60		9.70	0.339		0.382		
	Е	9.80		10.4	0.386		0.409		
	F	6.55		6.95	0.258		0.274		
	G		2.54			0.1			
	Н	28.0		29.8	1.102		1.173		
	L1		3.75			0.148			
	L2	1.14		1.70	0.045		0.067		
	L3	2.65		2.95	0.104		0.116		
	V1		45°			45°			

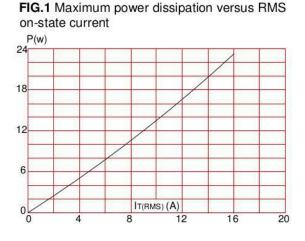
#### **TO-220 (Non-Ins) PACKAGE OUTLINE AND DIMENSIONS**

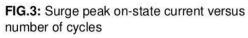


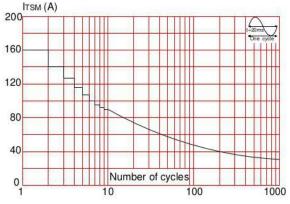




#### **CHARACTERISTIC CURVES**







**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<20ms, and corresponging value of  $I^2t$  (dI/dt < 50A/µs) ITSM (A),  $I^2t$  ( $A^2s$ )

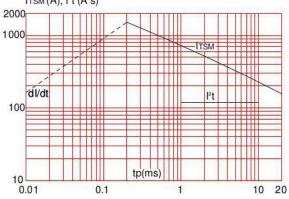
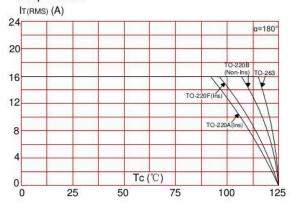
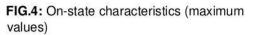
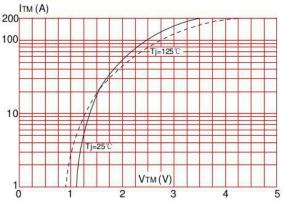


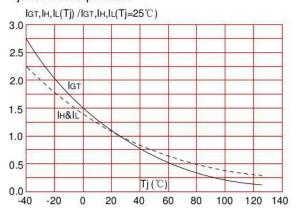
FIG.2: RMS on-state current versus case temperature







**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature







**Customer Notes** 

#### **Component Disposal Instructions**

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

#### DISCLAIMER

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of Continental Device India Pvt. Limited C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-2579 6150, 4141 1112 Fax + 91-11-2579 5290, 4141 1119 email@cdil.com www.cdil.com CIN No. U32109DL1964PLC004291

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Triacs category:

Click to view products by CDIL manufacturer:

Other Similar products are found below :

 T2035H-6G
 BT137-600-0Q
 Z0409MF0AA2
 Z0109NA 2AL2
 ACST1635T-8FP
 BCR20RM-30LA#B00
 CMA60MT1600NHR
 NTE5611

 NTE5612
 NTE5613
 NTE5623
 NTE5629
 NTE5638-08
 NTE5688
 NTE5690
 T1235T-8I
 BTA312-600CT.127
 T1210T 

 8G-TR
 Z0109NN0,135
 T2535T-8I
 T2535T-8T
 TN4050-12WL
 MAC4DLM-1G
 BT137-600E,127
 BT137X-600D
 BT148W-600R,115

 BT258-500R,127
 BTA08-800BW3G
 BTA140-800,127
 BTA30-600CW3G
 BTB08-800BW3G
 BTB16-600CW3G

 BTB16-600CW3G
 Z0410MF0AA2
 Z0109MN,135
 T825T-6I
 T1635T-6I
 T1220T-6I
 NTE5638
 TYN612MRG
 TYN1225RG
 TPDV840RG

 ACST1235-8FP
 ACS302-6T3-TR
 BT134-600D,127
 BT134-600G,127
 BT136X-600E,127